## BYW29-200

## Switch-mode Power Rectifiers

This state-of-the-art device is designed for use in switching power supplies, inverters and as free wheeling diodes.

#### **Features**

- 175°C Operating Junction Temperature
- Popular TO-220 Package
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Low Forward Voltage
- Low Leakage Current
- High Temperature Glass Passivated Junction
- Pb-Free Package is Available\*

#### **Mechanical Characteristics**

- Case: Epoxy, Molded, Epoxy Meets UL 94 V-0
- Weight: 1.9 Grams (Approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Device Meets MSL1 Requirements
- ESD Ratings: Machine Model, C (> 400 V) Human Body Model, 3B (> 8000 V)

### **MAXIMUM RATINGS**

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	200	٧
Average Rectified Forward Current Total Device, (Rated V <sub>R</sub> ), T <sub>C</sub> = 150°C	I <sub>F(AV)</sub>	8.0	Α
Peak Repetitive Forward Current (Rated $V_R$ , Square Wave, 20 kHz), $T_C = 150$ °C	I <sub>FM</sub>	16	Α
Nonrepetitive Peak Surge Current (Surge Applied at Rated Load Conditions Half-wave, Single Phase, 60 Hz)	I <sub>FSM</sub>	100	Α
Operating Junction Temperature and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-65 to +175	°C

#### THERMAL CHARACTERISTICS

Marian or Thermal Designation	_	0.0	°C/M
Maximum Thermal Resistance,	$H_{\theta JC}$	3.0	°C/00
Junction-to-Case			

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

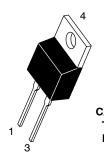


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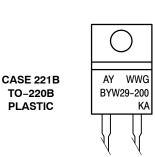
http://onsemi.com

## ULTRAFAST RECTIFIERS 8.0 AMPERES 200 VOLTS





#### MARKING DIAGRAM



A = Assembly Location

Y = Year

WW = Work Week

BYW80-200 = Device Code

G = Pb-Free Package

KA = Diode Polarity

### **ORDERING INFORMATION**

Device	Package	Shipping	
BYW29-200	TO-220	50 Units/Rail	
BYW29-200G	TO-220 (Pb-Free)	50 Units/Rail	

#### **ELECTRICAL CHARACTERISTICS**

Rating	Symbol	Value	Unit
Maximum Instantaneous Forward Voltage (Note 1) ( $i_F = 5.0 \text{ A}, T_C = 100^{\circ}\text{C}$ ) ( $i_F = 20 \text{ A}, T_C = 25^{\circ}\text{C}$ )	v <sub>F</sub>	0.85 1.3	V
Maximum Instantaneous Reverse Current (Note 1) (Rated Dc Voltage, $T_J$ = 100°C) (Rated Dc Voltage, $T_J$ = 25°C)	İR	600 5.0	μΑ
Maximum Reverse Recovery Time (I <sub>F</sub> = 1.0 A, di/dt = 50 A/ $\mu$ s) (I <sub>F</sub> = 0.5 A, i <sub>R</sub> = 1.0 A, I <sub>REC</sub> = 0.25 A)	t <sub>rr</sub>	35 25	ns

<sup>1.</sup> Pulse Test: Pulse Width = 300  $\mu$ s, Duty Cycle  $\leq$  2.0%.

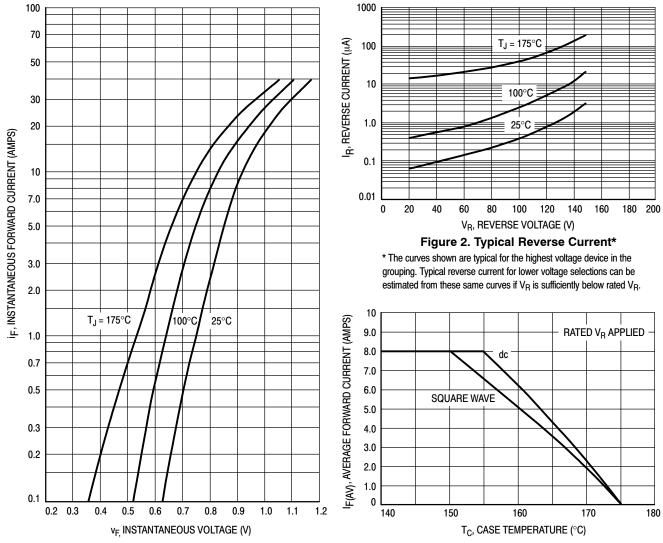
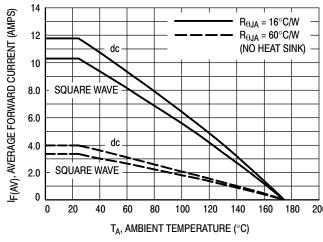


Figure 1. Typical Forward Voltage

Figure 3. Current Derating, Case

### BYW29-200



10 PF(AV), AVERAGE POWER DISSIPATION (WATTS) 9.0  $T_J = 175^{\circ}C$ 8.0 7.0 SQUARE WAVE 6.0 dc 5.0 4.0 3.0 2.0 1.0 2.0 3.0 4.0 5.0 6.0 7.0 8.0 9.0 10 I<sub>F(AV)</sub>, AVERAGE FORWARD CURRENT (AMPS)

Figure 4. Current Derating, Ambient

Figure 5. Power Dissipation

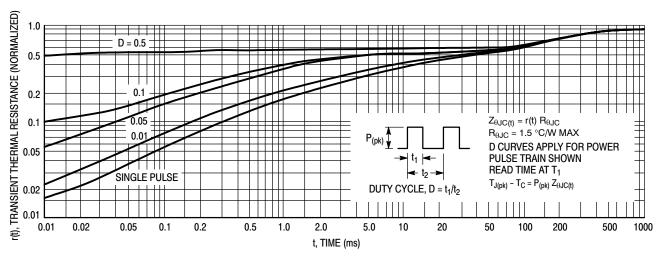


Figure 6. Thermal Response

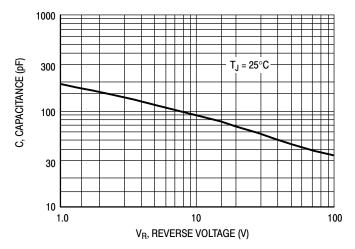
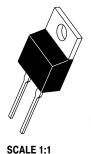


Figure 7. Typical Capacitance

# **MECHANICAL CASE OUTLINE**

**PACKAGE DIMENSIONS** 

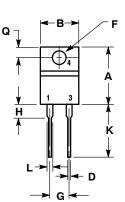


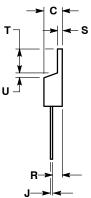


TO-220, 2-LEAD CASE 221B-04 ISSUE F

**DATE 12 APR 2013** 







#### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	INCHES		INCHES MILLIMET		IETERS
DIM	MIN	MAX	MIN	MAX	
Α	0.595	0.620	15.11	15.75	
В	0.380	0.405	9.65	10.29	
С	0.160	0.190	4.06	4.82	
D	0.025	0.039	0.64	1.00	
F	0.142	0.161	3.61	4.09	
G	0.190	0.210	4.83	5.33	
Н	0.110	0.130	2.79	3.30	
J	0.014	0.025	0.36	0.64	
K	0.500	0.562	12.70	14.27	
L	0.045	0.060	1.14	1.52	
Q	0.100	0.120	2.54	3.04	
R	0.080	0.110	2.04	2.79	
S	0.045	0.055	1.14	1.39	
Т	0.235	0.255	5.97	6.48	
U	0.000	0.050	0.000	1.27	

STYLE 1: PIN 1. CATHODE 2. N/A 3. ANODE

STYLE 2: PIN 1. ANODE 2. N/A 3. CATHODE 4. ANODE

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